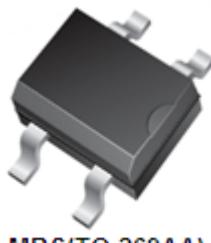
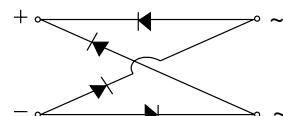


Surface Mount Bridge Rectifiers

Features

- Low forward voltage drop
- Ideal for automated placement
- Glass Passivated chip junction
- Low profile space
- Low leakage current
- High forward surge capability
- High temperature soldering:
260°C/10 seconds at terminals
- Component in accordance to
RoHS 2011/65/EU and WEEE 2002/96/EC


RoHS
COMPLIANT


MBS(TO-269AA)

Mechanical Data

- **Case:** MBS Molded plastic over glass passivated chip
- **Terminals:** Solder plated, solderable per
J-STD-002B and JESD22-B102D
- **Polarity:** Polarity symbols marked on body

Major Ratings and Characteristics

$I_{F(AV)}$	0.5A
V_{RRM}	50 V to 1000 V
I_{FSM}	35 A
I_R	5 μ A
V_F	1.0V
$T_J \text{ max.}$	150 °C

Maximum Ratings & Thermal Characteristics (TA = 25 °C unless otherwise noted)

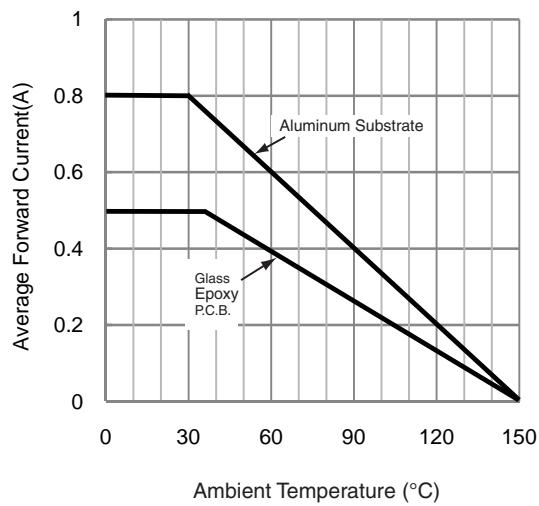
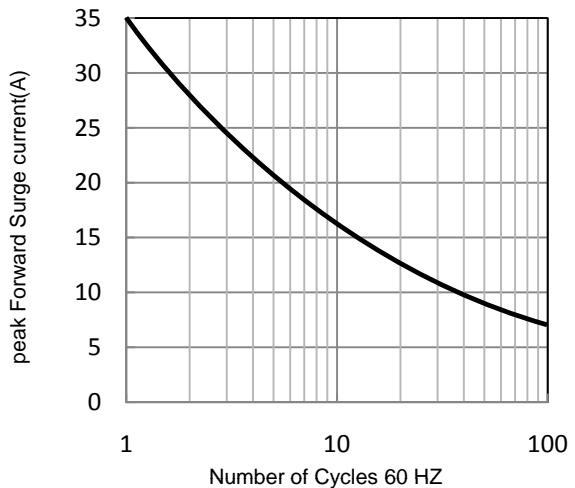
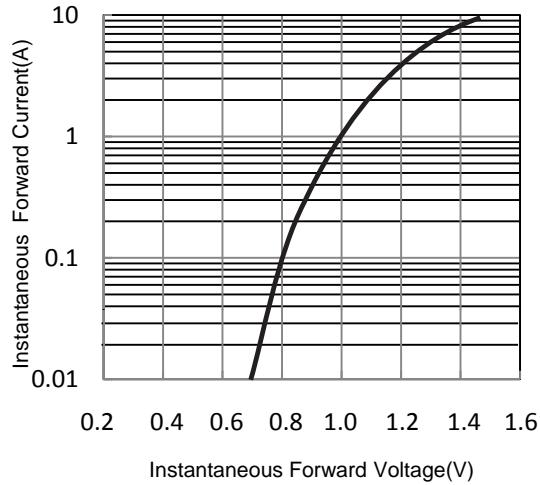
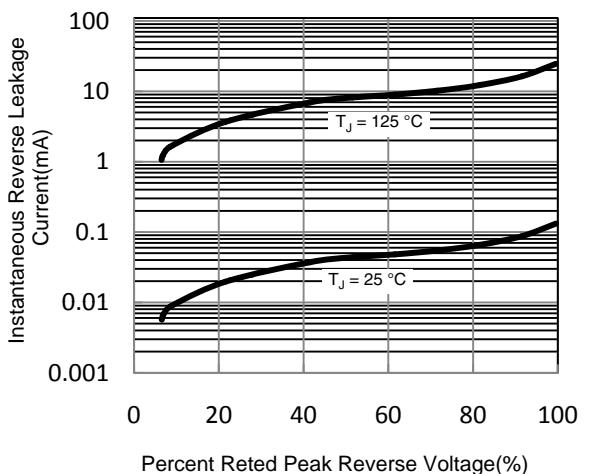
Items	Symbol	MB 05S	MB 1S	MB 2S	MB 4S	MB 6S	MB 8S	MB 10S	UNIT
Peak Repetitive Reverse Voltage	V_{RRM}								
Working Peak Reverse Voltage	V_{RWM}	50	100	200	400	600	800	1000	V
DC Blocking Voltage	V_R								
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Maximum average forward output rectified current (see Fig.1)	$I_{F(AV)}$				0.5 ⁽¹⁾ /0.8 ⁽²⁾				A
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load(JEDEC Method)	I_{FSM}				35				A
Thermal resistance from junction to lead	$R_{\theta JL}$				20 ⁽¹⁾				°C/W
Thermal resistance from junction to ambient	$R_{\theta JA}$				85 ⁽¹⁾ 70 ⁽²⁾				°C/W
Operating junction and storage temperature range	T_J, T_{STG}				-55 to +150				°C

Notes: (1)On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3 mm) pads

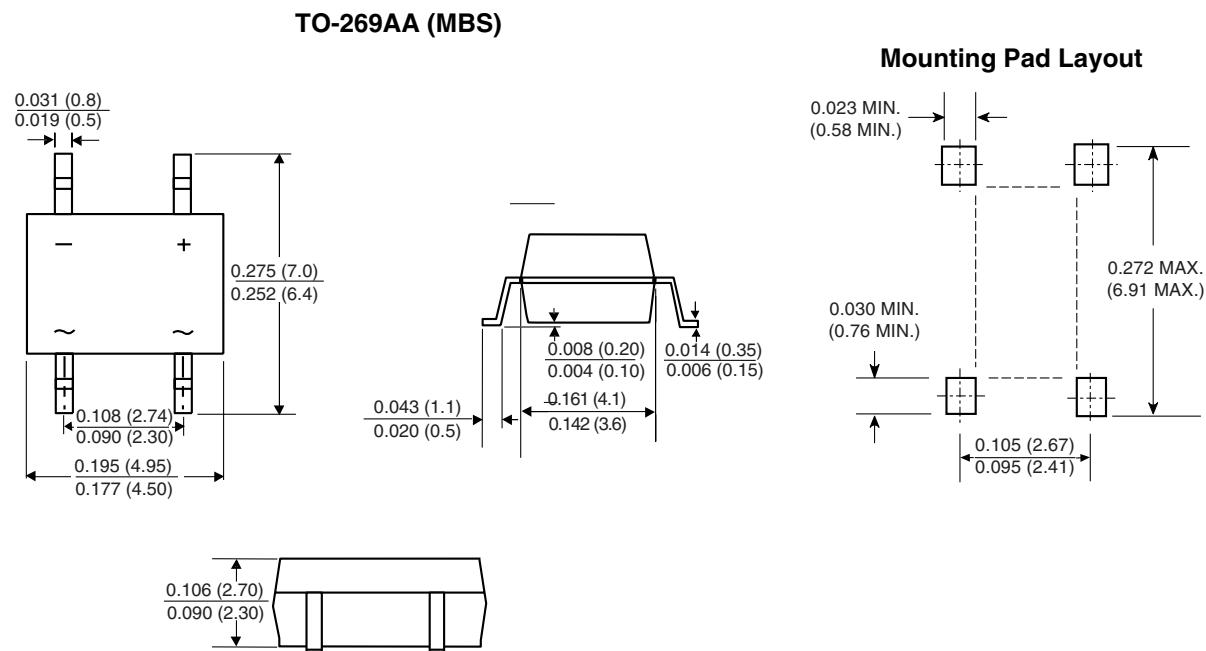
(2)On aluminum substrate P.C.B. with an area of 0.8" x 0.8" (20 x 20 mm) mounted on 0.05 x 0.05" (1.3 x 1.3 mm) solder pad

Electrical Characteristics (TA = 25 °C unless otherwise noted)

Items	Test conditions		Symbol	Min	Type	Max	UNIT
Maximum instantaneous forward voltage drop per leg	$I_F=0.4A$		V_F	-	-	1.0	V
Reverse current	$V_R=V_{DC}$	$T_A=25^\circ C$	I_R	-	-	5	μ A
		$T_A=125^\circ C$		-	-	100	
Typical junction capacitance	4.0 V ,1MHz		C_J	-	13	-	p F

Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)
Fig.1 Forward Current Derating Curve

Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

Fig.3 Typical Instantaneous Forward Characteristics

Fig.4 Typical Reverse Leakage Characteristics


Package Outline



Dimensions in millimeters and (inches)

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